BCP68; BC868; BC68PA

20 V, 2 A NPN medium power transistors Rev. 8 — 18 October 2011

Product data sheet

Product profile

1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number[1]	Package		PNP complement	
	NXP	JEITA	JEDEC	
BCP68	SOT223	SC-73	-	BCP69
BC868	SOT89	SC-62	TO-243	BC869
BC68PA	SOT1061	-	-	BC69PA

^[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Two current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	20	V
I _C	collector current		-	-	2	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	3	Α



Table 2. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
h_{FE}	DC current gain	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<u>1</u> 85	-	375	
	h _{FE} selection -25	$V_{CE} = 1 \text{ V}; I_{C} = 500 \text{ mA}$	<u>1</u> 160	-	375	

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta = 0.02.$

2. Pinning information

Table 3. Pinning

Pin	Description	Simplified outline	Graphic symbol
	Description	Simplified outline	Grapine Symbol
SOT223			
1	base		2, 4
2	collector	4	2, 4
3	emitter		1—
4	collector	1 2 3	3
			sym016
SOT89			
1	emitter		_
2	collector		2
3	base	3 2 1	3 — 1 sym042
SOT1061			
1	base		
2	emitter	3	3
3	collector	1 2 Transparent top view	12 sym021

3. Ordering information

Table 4. Ordering information

Type number[1]	Package					
	Name	Description	Version			
BCP68	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			
BC868	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89			
BC68PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2\times2\times0.65$ mm	SOT1061			

^[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes

Marking code
BCP68
BCP68/25
CAC
CDC
AR
AS

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

			-		
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	32	V
V_{CEO}	collector-emitter voltage	open base	-	20	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current		-	2	Α
I _{CM}	peak collector current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	3	Α
I _B	base current		-	0.4	Α
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	0.4	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	BCP68		<u>[1]</u> _	0.65	W
			[2]	1.00	W
			[3]	1.35	W
	BC868		<u>[1]</u> _	0.50	W
			[2]	0.95	W
			[3]	1.35	W
	BC68PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			<u>[4]</u> _	0.81	W
			<u>[5]</u> _	1.65	W
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

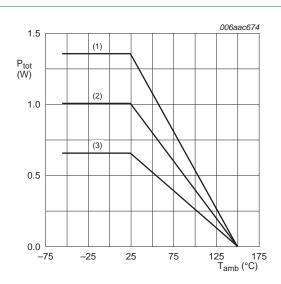
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

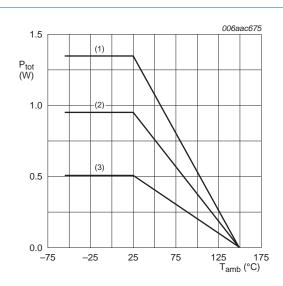
^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



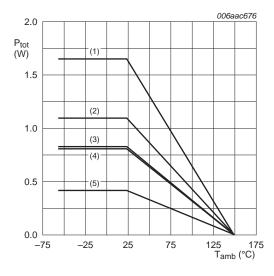
- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 1. Power derating curves SOT223



- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 2. Power derating curves SOT89



- (1) FR4 PCB, 4-layer copper, mounting pad for collector 1 cm²
- (2) FR4 PCB, single-sided copper, mounting pad for collector 6 cm²
- (3) FR4 PCB, single-sided copper, mounting pad for collector 1 cm²
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 3. Power derating curves SOT1061

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	BCP68		<u>[1]</u> _	-	192	K/W
			[2] _	-	125	K/W
			[3]	-	93	K/W
	BC868		<u>[1]</u> _	-	250	K/W
			[2] _	-	132	K/W
			[3] _	-	93	K/W
	BC68PA		<u>[1]</u> _	-	298	K/W
			[2] _	-	151	K/W
			[3] _	-	114	K/W
			<u>[4]</u> _	-	154	K/W
			<u>[5]</u> _	-	76	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point					
	BCP68		-	-	16	K/W
	BC868		-	-	16	K/W
	BC68PA		-	-	20	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².

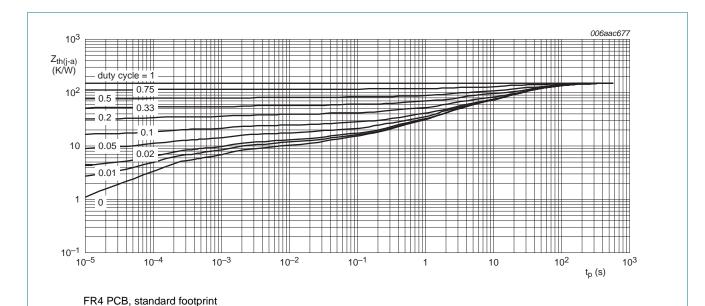
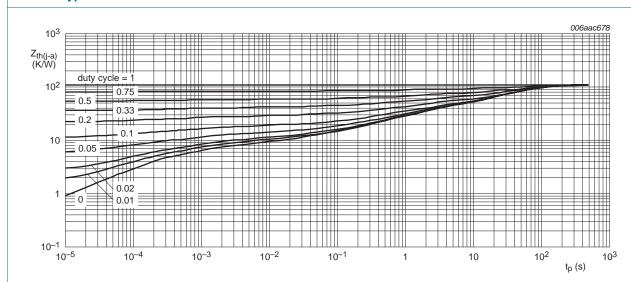
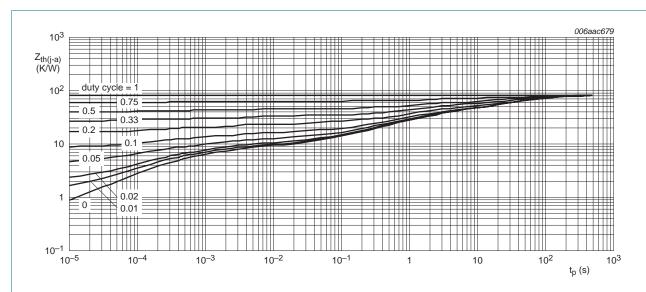


Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



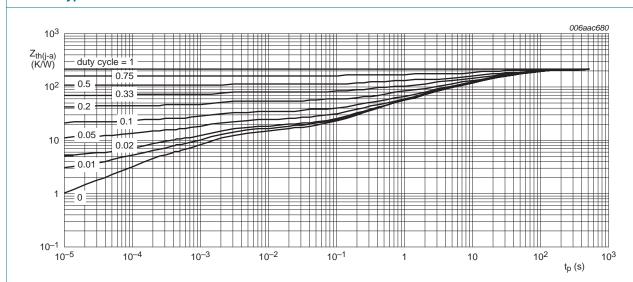
FR4 PCB, mounting pad for collector 1 cm²

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, mounting pad for collector 6 cm²

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, standard footprint

Fig 7. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

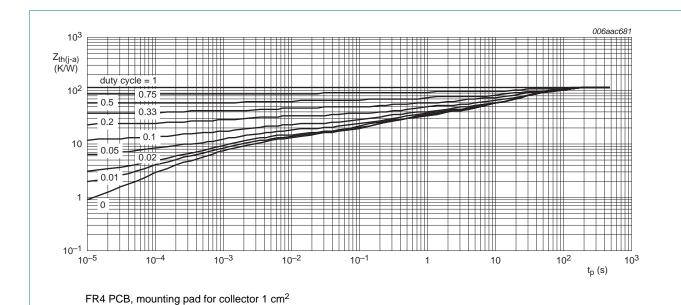
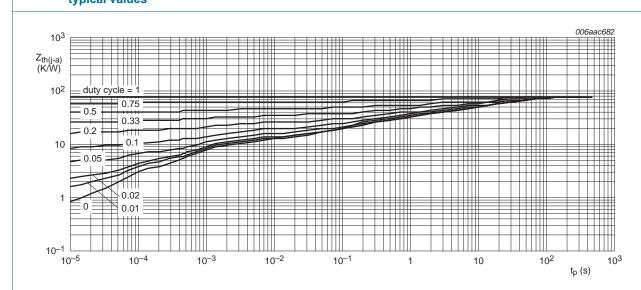
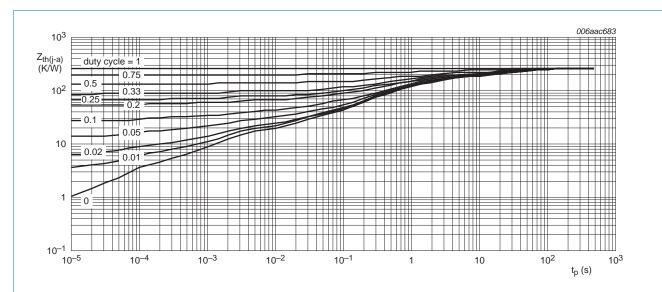


Fig 8. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values



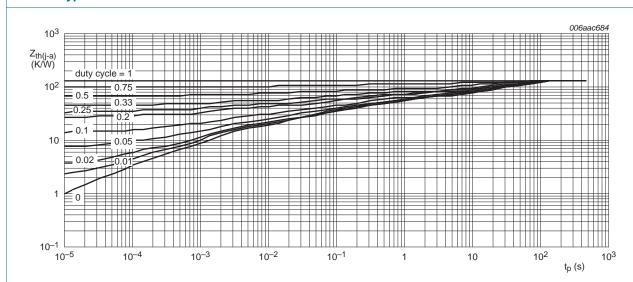
FR4 PCB, mounting pad for collector 6 cm²

Fig 9. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values



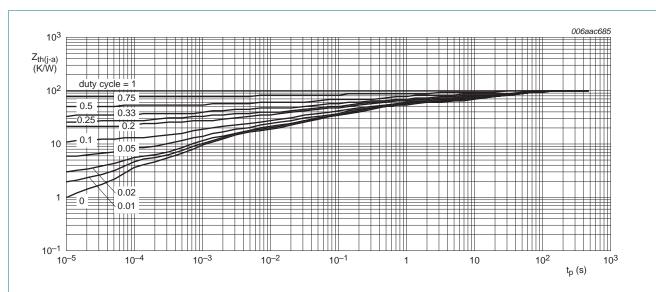
FR4 PCB, single-sided copper, standard footprint

Fig 10. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



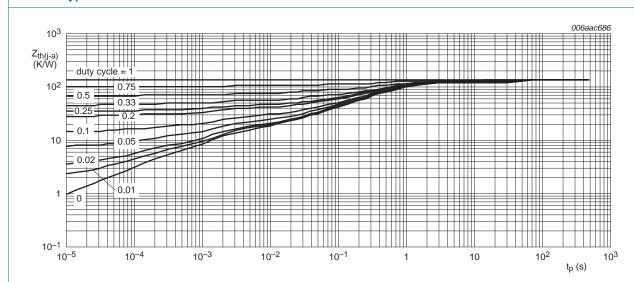
FR4 PCB, single-sided copper, mounting pad for collector 1 cm²

Fig 11. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



FR4 PCB, single-sided copper, mounting pad for collector 6 cm²

Fig 12. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig 13. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

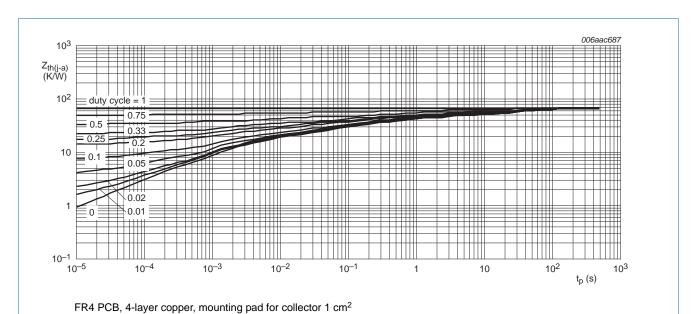


Fig 14. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

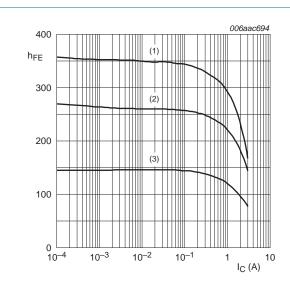
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off	$V_{CB} = 25 \text{ V}; I_E = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 25 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_C = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 10 V					
		$I_C = 5 \text{ mA}$		50	-	-	
	DC current gain	V _{CE} = 1 V					
		$I_C = 500 \text{ mA}$	[1]	85	-	375	
		I _C = 1 A	[1]	60	-	-	
		I _C = 2 A	[1]	40	-	-	
	DC current gain	V _{CE} = 1 V					
	h _{FE} selection -25	$I_C = 500 \text{ mA}$	<u>[1]</u>	160	-	375	
V _{CEsat}	collector-emitter	$I_C = 1 A; I_B = 100 \text{ mA}$	[1]	-	-	0.5	V
	saturation voltage	$I_C = 2 \text{ A}; I_B = 200 \text{ mA}$	[1]	-	-	0.6	V
V_{BE}	base-emitter voltage	V_{CE} = 10 V; I_{C} = 5 mA	<u>[1]</u>	-	-	0.7	V
		$V_{CE} = 1 \text{ V}; I_{C} = 1 \text{ A}$	<u>[1]</u>	-	-	1	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	22	-	pF
f⊤	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA};$ f = 100 MHz		40	170	-	MHz
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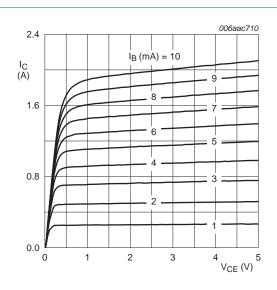
^[1] Pulse test: $t_p \le 300~\mu s;~\delta = 0.02.$



$$V_{CE} = 1 V$$

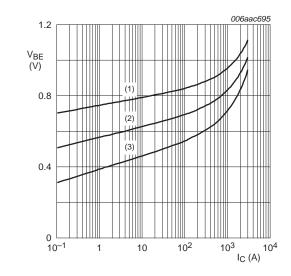
- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 15. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

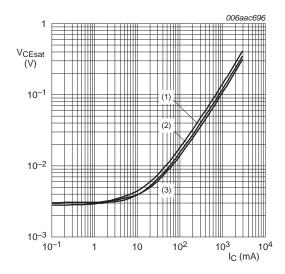
Fig 16. Collector current as a function of collector-emitter voltage; typical values





- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 100 \, ^{\circ}C$

Fig 17. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 18. Collector-emitter saturation voltage as a function of collector current; typical values

4.25 3.75

€ 06-08-29

1.2

0.48 0.35

8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

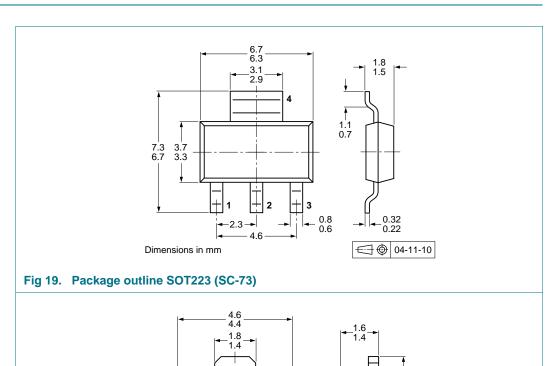


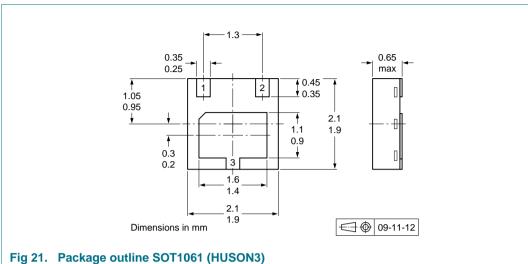
Fig 20. Package outline SOT89 (SC-62/TO-243)

2.6 2.4

0.53

-1.5

Dimensions in mm



10. Packing information

Packing methods Table 9.

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package	Description		Packing quantity		
number[2]				1000	3000	4000
BCP68	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BC868	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC68PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

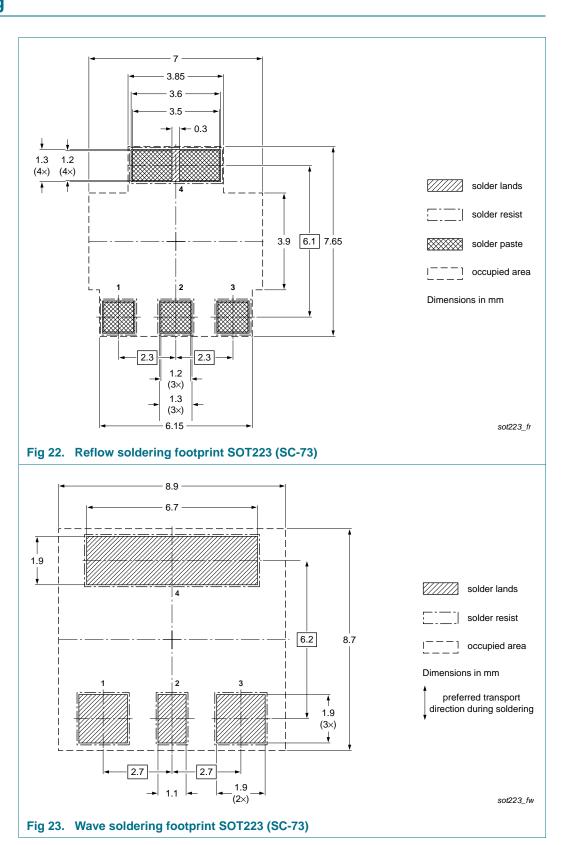
For further information and the availability of packing methods, see Section 14.

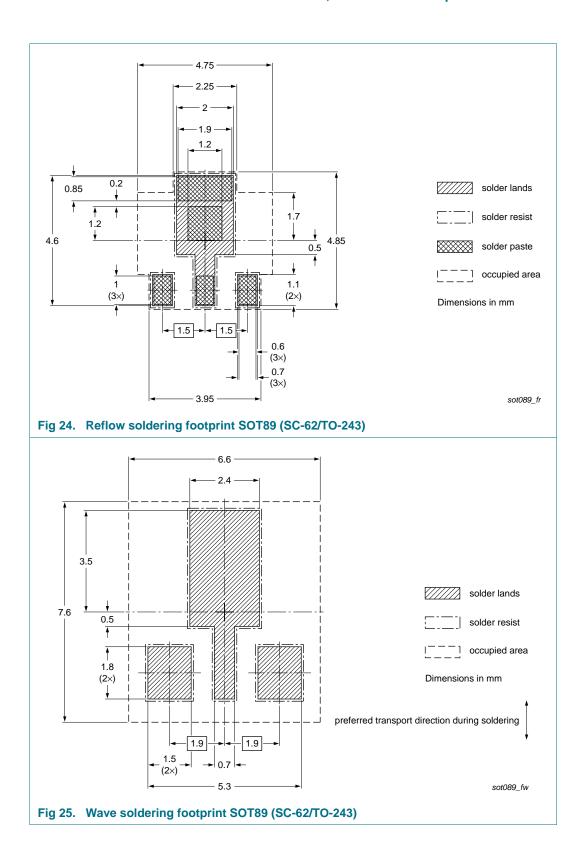
Valid for all available selection groups.

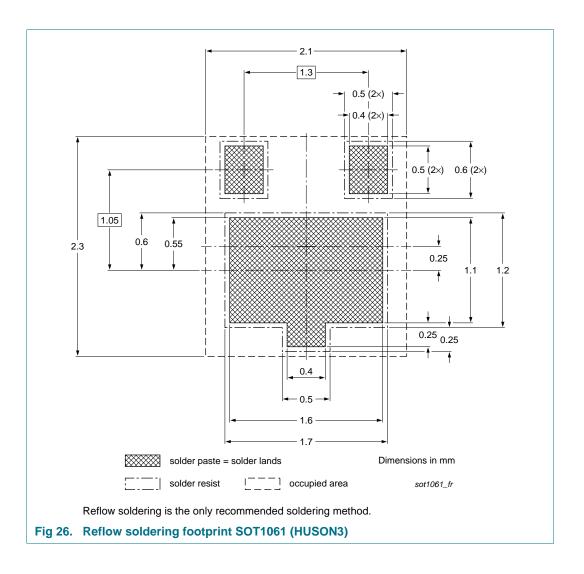
T1: normal taping

T3: 90° rotated taping

11. Soldering







12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BCP68_BC868_BC68PA v.8	20111018	Product data sheet	-	BC868 v.7			
				BCP68 v.4			
Modifications:		of this document has been of NXP Semiconductors.	en redesigned to comp	bly with the new identity			
	 Legal texts 	have been adapted to th	e new company name	where appropriate.			
	 Type numb 	er BC68PA added					
	Section 1 "	Product profile": updated					
	Section 2 "	Pinning information": upd	ated				
	Section 3 "Ordering information": updated						
	 Section 4 " 	Marking": updated					
	Section 8 "Test information": added						
	 Section 9 "Package outline": updated 						
	 Section 10 "Packing information": added 						
	Section 11 "Soldering": added						
	• Table 6, 7 and 8: updated according to latest measurements						
	• Figure 1, 2, 6, 8, 15 to 18: updated						
	• Figure 3, 4	, <u>5</u> , <u>7</u> , <u>9</u> , <u>10</u> to <u>13</u> : added					
BC868 v.7	20041108	Product specification	-	BC868 v.6			
BC868 v.6	20031202	Product specification	-	BC868 v.5			
BC868 v.5	19990408	Product specification	-	BC868 v.4			
BC868 v.4	19980716	Product specification	-	BC868_CNV v.3			
BC868_CNV v.3	19970319	Product specification	-	BC868_CNV v.2			
BC868_CNV v.2	19970307	Product specification	-	-			
BCP68 v.4	20031125	Product specification	-	BCP68 v.3			
BCP68 v.3	19990408	Product specification	-	BCP68_CNV v.2			
BCP68_CNV v.2	19970409	Product specification	-	•			
20. 00_0.11 1.2	10070100	1 10000 opcomoditori					

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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BCP68 BC868 BC68PA

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BCP68; BC868; BC68PA

20 V, 2 A NPN medium power transistors

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

15. Contents

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.